AIXTRON Investor Presentation



IR Presentation – 9M/2019 (FSE: AIXA, ISIN DE000A0WMPJ6)



DISCLAIMER 2

Forward-Looking Statements

This document may contain forward-looking statements regarding the business, results of operations, financial condition and earnings outlook of AIXTRON. These statements may be identified by words such as "may", "will", "expect", "anticipate", "contemplate", "intend", "plan", "believe", "continue" and "estimate" and variations of such words or similar expressions. These forward-looking statements are based on the current assessments, expectations and assumptions of the executive board of AIXTRON, of which many are beyond control of AIXTRON, based on information available at the date hereof and subject to risks and uncertainties. You should not place undue reliance on these forward-looking statements. Should these risks or uncertainties materialize, or should underlying expectations not occur or assumptions prove incorrect, actual results, performance or achievements of AIXTRON may materially vary from those described explicitly or implicitly in the relevant forward-looking statement. This could result from a variety of factors, such as those discussed by AIXTRON in public reports and statements, including but not limited those reported in the chapter "Risk Report". AIXTRON undertakes no obligation to revise or update any forward-looking statements as a result of new information, future events or otherwise, unless expressly required to do so by law. This document is an English language translation of a document in German language. In case of discrepancies, the German language document shall prevail and shall be the valid version.

Due to rounding, numbers presented throughout this report may not add up precisely to the totals indicated and percentages may not precisely reflect the absolute figures for the same reason.

Our registered trademarks: AIXACT[®], AIXTRON[®], APEVA[®]; Atomic Level SolutionS[®], Close Coupled Showerhead[®], CRIUS[®], EXP[®], EPISON[®], Gas Foil Rotation[®], Optacap[™], OVPD[®], Planetary Reactor[®], PVPD[®], STExS[®], TriJet[®]



ABOUT AIXTRON

Our Vision

Technology. Materials. Performance.

Technology.

We are the **recognized technology leader** in complex material deposition.

Materials.

We **enable our customers** to
successfully shape the
markets of the future,
exploiting the potential
offered by **new materials**.

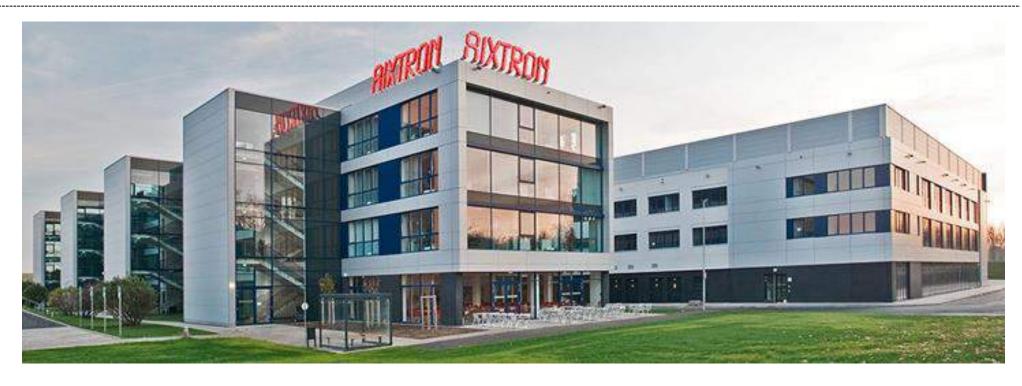
Performance.

We deliver the performance driving economic success through our expertise, our employees and the quality of our products.



ABOUT AIXTRON

Who we are



- Headquarters based near Aachen, Germany
- Worldwide presence in 7 countries
- R&D and production facilities in Germany and UK
- ~ 700 employees

- Company founded in 1983, >35 years of experience
- Technology leader in deposition systems
- Around 3,500 deposition systems sold worldwide



Where we are



ABOUT AIXTRON 6

What We Do



We provide enabling **Deposition Equipment to the Compound Semiconductor and Display Industry**

For Optoelectronics and Power Electronics

- Metal-Organic Chemical Vapor Deposition (MOCVD)
 for the deposition of compound materials to produce for
 instance Lasers, LEDs, GaN and SiC Power Electronics or
 other Optoelectronic components
- Plasma-enhanced Chemical Vapor Deposition (PECVD) for the deposition of Carbon Nanostructures and 2D materials (Carbon Nanotubes, Nanowires or Graphene)

For Organic Electronics Applications

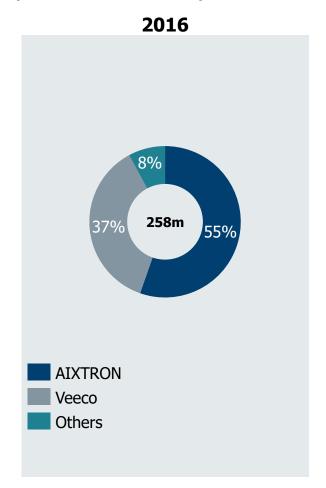
Organic Vapor Phase Deposition (OVPD)
 for the deposition of Organic Light Emitting Diodes (OLED)
 based displays for smartphones to TV

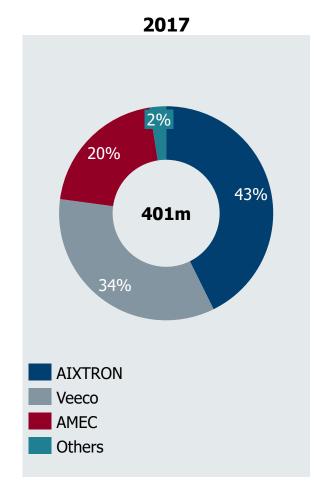
These thin film deposition technologies are offered by AIXTRON's subsidiary APEVA.

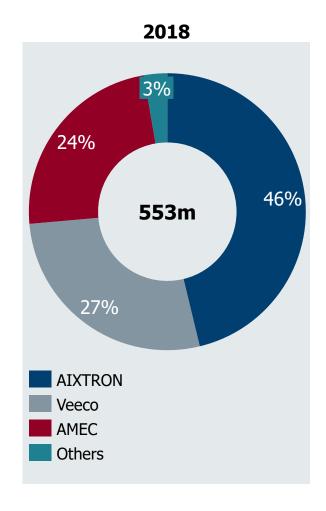


Our MOCVD Market Position

(Market Size in USD)







Source: Gartner "Market Share: Semiconductor Wafer Fab Equipment, Worldwide, 2018" (publ. April, 2019)



Power Management

Technology Portfolio for Complex Material Deposition

OLED: OVPD®/PVPD®





Carbon - PECVD

NANO: Innovation Pool



Lasers (VCSEL/EEL)

(e.g. 3D Sensing; Consumer Electronics; Optical Datacom, LIDAR)



GaN Power | GaN RF

(e.g. Wireless Charging, Fast Charging, Power Supply, 5G Network)



Specialty LEDs

(e.g. Fine Pitch-, MiniLED-, Horticulture; Purification, next-gen MicroLED-Displays)



SiC Power

(e.g. Electric Vehicles, Charging Stations, Infrastructure)

MOCVD Core Technology



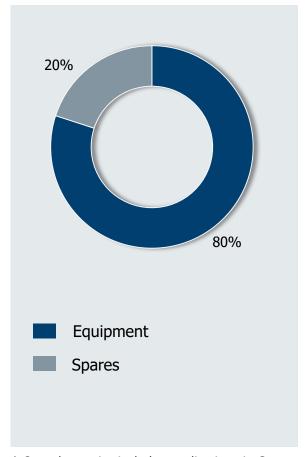
Key Financials Q3/2019*

(€ million)	9M/19	9M/18	+/- %	Q3/19	Q2/19	+/- %
Order intake	150.6	230.3	-35	52.2	44.7	17
Order backlog (equipment only)	108.4	151.9	-29	108.4	110.1	-2
Revenues	184.6	180.9	2	52.6	63.3	-17
Gross profit	74.7	78.2	-4	22.1	25.9	-15
%	40	43	-3 pp	42	41	1 pp
EBIT	24.5	20.7	18	5.5	9.3	-41
%	13	11	2 pp	10	<i>15</i>	-5 pp
Net result	20.2	27.7	-27	4.4	7.3	-40
%	11	<i>15</i>	-4 pp	8	<i>12</i>	-4 pp
Net result per share (EUR)	0.18	0.25	-28	0.04	0.14	-71
Free Cash Flow	-2.7	-1.4	-93	2.3	12.6	-82

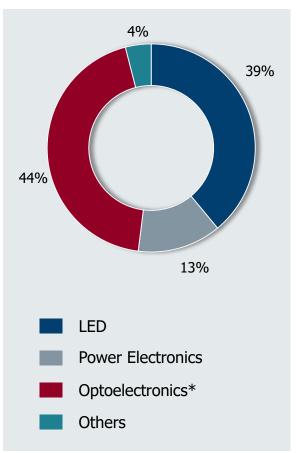


Revenue Analysis*

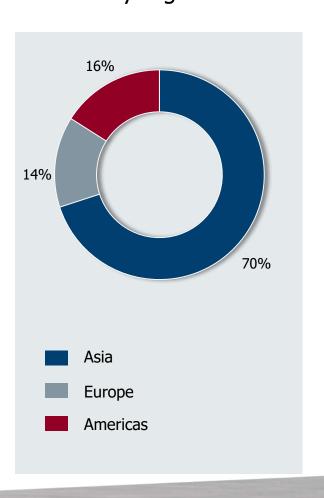
9M/2019: by equipment & spares



9M/2019: by end application (equipment only)



9M/2019: by region





 $[\]hbox{* Optoelectronics includes applications in Consumer Optoelectronics, Telecom/Datacom\ and\ Solar}\\$

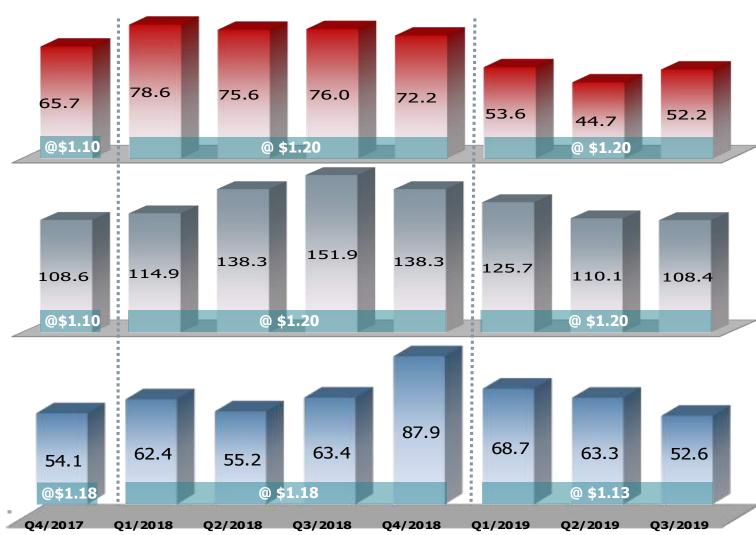
24 - Month Business Development

(€ million)

Order Intake (incl. equipment, service, spare parts)

Order Backlog (equipment only)

Revenues (incl. equipment, service, spare parts)



USD order intake and backlog were recorded at the prevailing budget rate (2017: \$1.10/€; 2018/2019: \$1.20/€) USD revenues were converted at the actual period average FX rate (2017: \$1.18/€; 2018: \$1.18/€; 2019: \$1.13/€)



Consolidated Income Statement*

(€ million)	9M/19	9M/18	+/- %	Q3/19	Q2/19	+/- %
Revenues	184.6	180.9	2	52.6	63.3	-17
Cost of sales	109.8	102.7	7	30.4	37.4	-19
Gross profit	74.7	78.2	-4	22.1	25.9	-15
%	40	43	-3 pp	42	41	1 pp
Selling expenses	7.1	6.7	6	2.4	2.4	-
General & admin expenses	12.4	13.3	-7	4.3	4.3	-
R&D	40.0	40.0	0	14.7	12.5	18
Net other operating income	(9.4)	(2.5)	276	(4.7)	(2.7)	74
EBIT	24.5	20.7	23	5.5	9.3	-41
%	13	11	2 pp	10	15	-5 pp
Net result	20.2	27.7	-27	4.4	7.3	-40
%	11	15	-4 pp	8	12	-4 pp



Balance Sheet*

(€ million)	30/09/19	30/06/19	31/12/18
Property, plant & equipment	64.8	64.6	63.1
Goodwill	72.2	71.7	71.6
Other intangible assets	2.2	2.3	2.1
Others	12.5	12.4	13.3
Non-current assets	151.8	151.0	150.1
Inventories	87.9	81.8	73.5
Trade receivables	33.2	28.0	40.1
Others	6.5	7.4	11.5
Cash & Cash Deposits	260.6	258.9	263.7
Current Assets	388.2	376.1	388.8
Equity	451.0	446.3	429.7
Non-current liabilities	4.8	4.7	1.8
Trade payables	14.0	11.2	27.8
Advance payments from customers	44.4	38.9	53.3
Others	25.9	26.0	26.3
Current liabilities	84.3	76.1	107.4
Balance Sheet total	540.1	527.1	538.9



Consolidated Statement of Cash Flows*

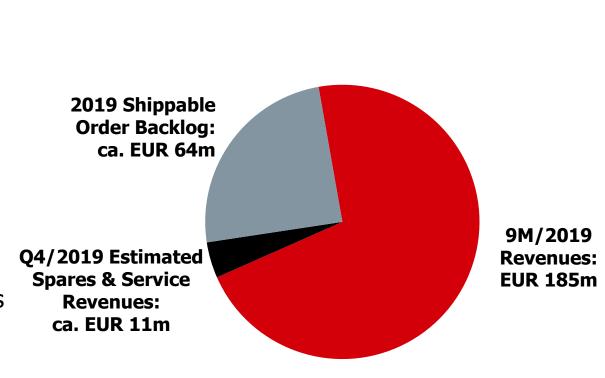
(€ million)	9M/19	9M/18	Q3/19	Q2/19
Net Result	20.2	27.7	4.4	7.3
Adjust for				
Non Cash Items	9.0	-0.1	2.8	3.8
Changes in Working Capital	-22.7	-22.2	-2.4	2.5
Cash Flow from Operating Activities	6.5	5.4	4.9	13.6
Capital Expenditures/Disposals	-9.2	-6.8	-2.6	-1.0
Free Cash Flow	-2.7	-1.4	2.3	12.6
FX Effects	-0.5	0.2	-0.6	-1.6
Cash & Deposits	260.6	245.4	260.6	258.9



AIXTRON – 2019 Guidance*: Firmed Up

2019 Guidance* firmed up with Orders, Revenues, FCF now at the lower end of the range, taking 9M-Results and the current order/revenue situation into account:

- Total Order Intake around EUR 220 million (vs. 220m ~ 260m previously)
- Revenues around EUR 260 million (vs. 260m ~ 290m previously)
- Gross Margin around 40% of Revenues
- EBIT Margin around 13% of Revenues
- Free Cash Flow around EUR 15 million (vs. 15m ~ 25m previously)



2019 Guidance*

^{*} At 1.20 USD/EUR Budget Rate for the remainder of the year; please refer to "Expected Results of Operations and Financial Position" in the AIXTRON 2018 Annual Report for further information



FUTURE MARKETS 16

Market Prospects

Short- to Mid-Term

• Increasing adoption of compound semiconductor-based lasers for 3D sensor systems in mobile devices as well as sensors for infrastructure applications.

- Further increasing demand for lasers for ultra-fast optical data transmission of large volumes, such as for video streaming and Internet-of-Things (IoT) applications.
- Increasing use of LEDs and specialty LEDs (esp. red-orange-yellow, UV or IR) in displays and other applications.
- Increasing use of wide-band gap GaN- or SiC-based components for energy-efficient communication and power management in autos, consumer electronics and mobile devices.
- Progress in the development of OLED displays that require an efficient deposition technology.

Long-Term

- Development of new applications based on wide-band gap materials such as high-frequency chips or system-on-chip architectures with integrated power management.
- Increased use of compound semiconductor-based sensors for autonomous driving.
- Increased development activities for high performance solar cells made of compound semi-conductors.
- Development of new materials with the help of carbon nanostructures (carbon nanotubes, -wires and graphene).
- Development of alternative LED applications, such as visual-light communication technology or micro LED displays.



AIXTRON INVESTOR PRESENTATION 17

Our technology. YOUR FUTURE.



AIXTRON MOCVD – Planetary Reactor®: Tool-of-Record

- ✓ Individual Wafer Rotation = Best Material Uniformity
- ✓ Individual wafer temperature adjustment = Wafer Level Control/Optimization
- ✓ Highest Epi / Product Yield = Lowest Production Cost

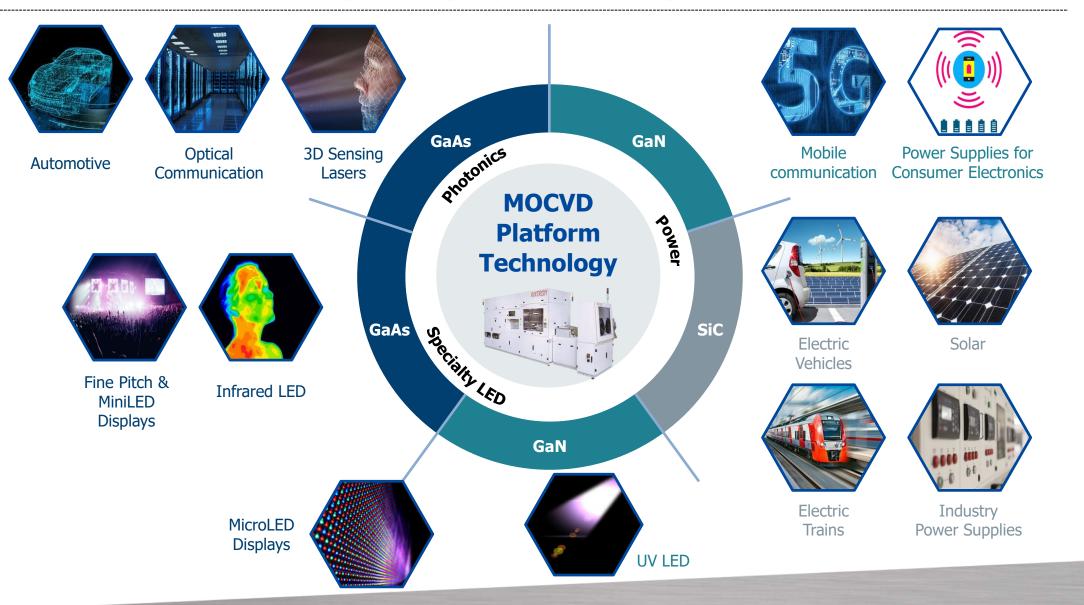








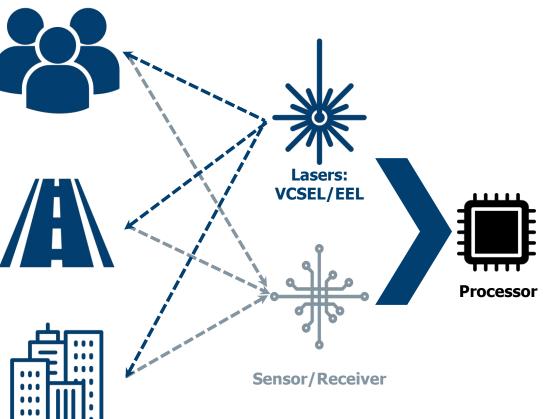
AIXTRON – Enabling Emerging Global Mega Trends





Devices: VCSEL/EEL – Internet of Things Creates New Opportunities

3D Sensing Functionality





Facial Recognition



Autonomous Driving



Tailor-made clothing/shoes



Interior Design



Mapping



Industry 4.0

Devices: GaN/SiC Power Electronics – Superior Performance



Smaller

Energy Saving

Less Heat

Light Weight

Lower







EV-charging







Renewable Energy





Fast Charging



Devices: ROY LEDs for RGB* Displays; UV LEDs for Niche Markets

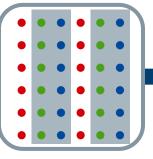
Source: LEDinside, Yole Développement

Initial

Introduction

Expected

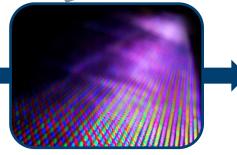
RGB* LED DISPLAYS











Stadium Outdoor Display

(Pixel Pitch ≥10mm) (Chip size: ≥ 200μm)

Fine Pitch Indoor Display

(Pixel Pitch ≤2.5mm) (Chip size: ≥ 200µm)

MiniLED for Consumer Electronics

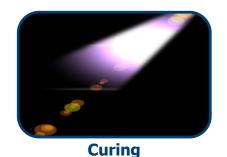
(Chip size: $\leq 200 \mu m$)

MicroLED for Consumer Electronics

(Chip size: $\leq 50 \mu m$)





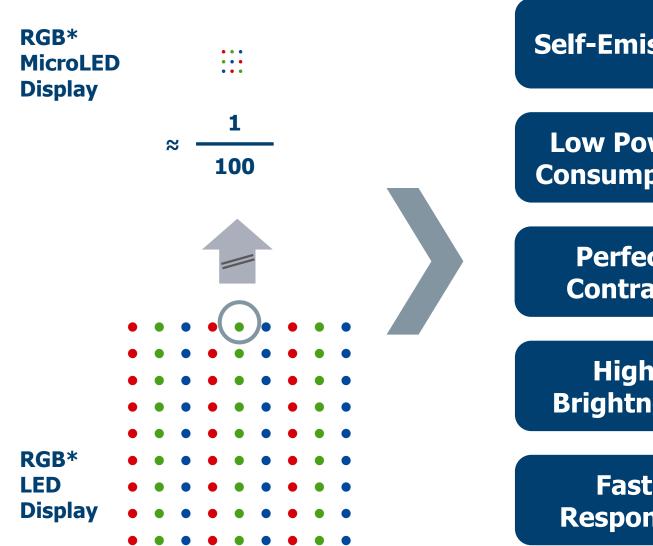






Air Purifier

Devices: MiniLED & MicroLED – The Perfect Future Display Technology



Self-Emissive

Low Power Consumption

> **Perfect Contrast**

High **Brightness**

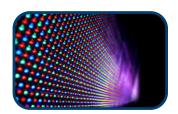
Fast Response



Wearables



AR/VR

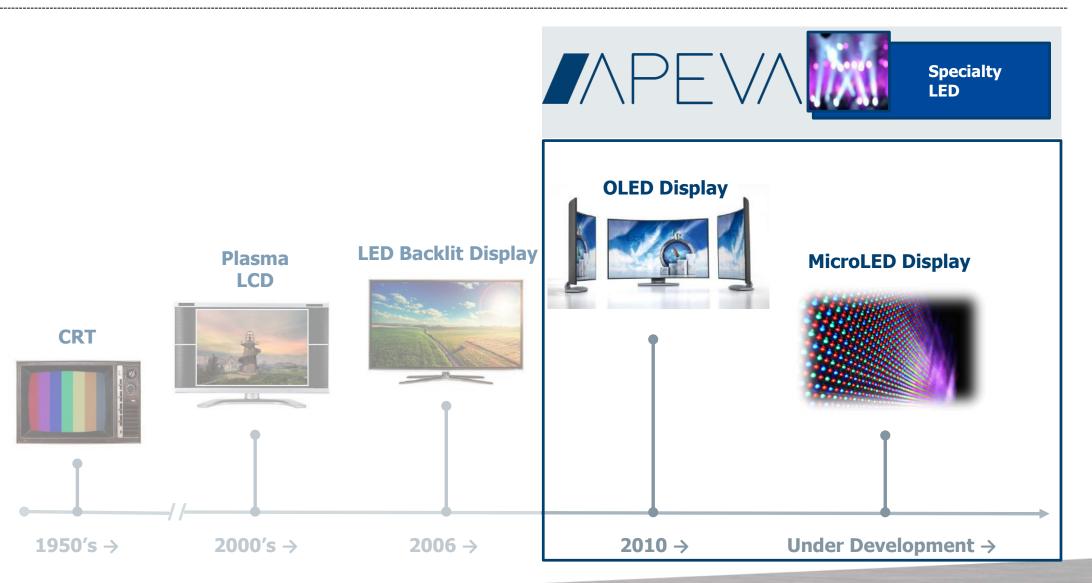


Signage



Smartphones/Tablets/TVs

AIXTRON – Instrumental in Evolving Display Technologies

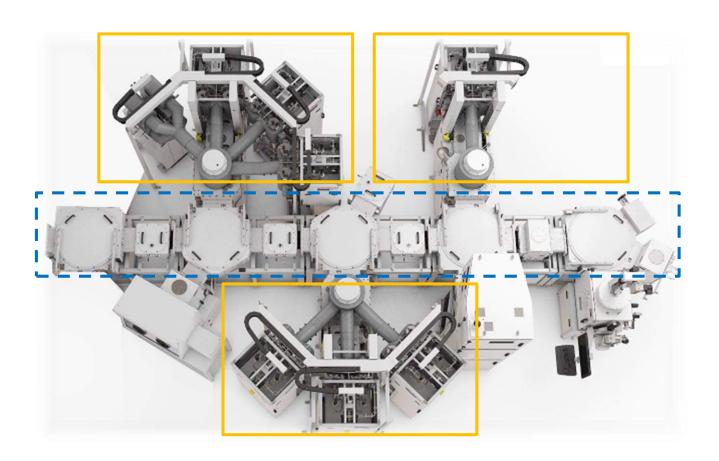






APEVA: Complete OLED Deposition System Provider

OVPD Deposition Line*











- Fully Automated OLED **Deposition Lines and Fab** Integration as a Complete System Provider
- Innovative Deposition Technology with
 - Higher Efficiency of OLED **Material Deposition**
 - Mixing and Doping of Materials via Multiple Material Deposition in One Chamber
 - Maintaining the Delicate **Organic Material Properties** improving Lifetime





Organic Electronics – OVPD® – APEVA

Source: DisplaySearch, AIXTRON **OLED manufacturing process** Cleaning Cleaning **Glass cutting ITO deposition Organic material Bonding** deposition **Coating Etching Cathode deposition Aging Stripping Encapsulation Final test** (Thin film; TFE) **Test and repair** Front-end **Front-end Back-end Cell process equipment Array process equipment Module process equipment** In Qualification for Volume Production

Carbon Nanomaterials – PECVD

Graphene and Carbon Nanotube Deposition Systems

- Proprietary thermal and plasma enhanced chemical vapor deposition technology
- Excellent uniformity and reproducibility with fast turnaround cycle times
- BM platform: BM R&D (2-inch), BM Pro (4-inch and 6-inch), BM GB (4-inch glovebox), BM HT (high temperature, 1,700C), BM300T (300mm)
- Graphene and carbon nanotube films for electronics, energy storage, thermal management, sensors and flexible/transparent applications

Product features

- Fast response heater and turnaround
- Thermal CVD
- Substrate and top heating
- Closed loop infrared wafer temperature control
- Plasma enhanced CVD with frequency control
- Flexible processing for different applications
- Low cost of ownership
- · Easy maintenance and cleaning
- User management features and growth library

Material Properties



AIXTRON Technology



Enabling Applications



Graphene (2D) and Carbon nanotube (1D)

Unique combination of high electrical/ thermal conductivity, mobility, flexibility and transparency



Serving R&D market today
AIXTRON BM Pro



Production ready for tomorrow AIXTRON BM Pro 300



Low to Medium Voltages

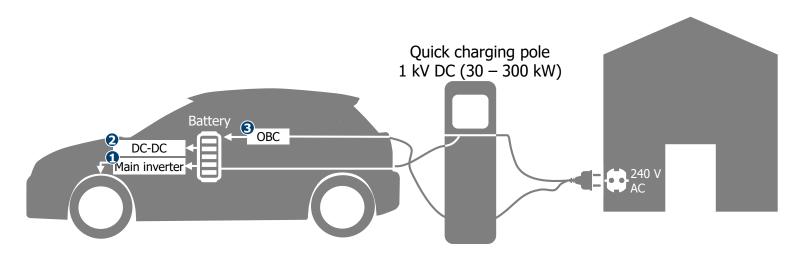
Overview: GaN/SiC as Wide Band Gap (WBG) Power Electronics

Consumer Electronics & IT Automotive Industrial Energy Power Management Power Switching 30V 600V 1.2 kV ≥2kV • UPS Infotainment General automotive Electronic appliances Power Grid / Smart meter / appliances Industrial machines Computing • GPS electronic • HEV/EV Solar / Wind inverters Building · Wireless charging · Connected car · Mining, oil, gas Charging station Solar / Wind power Power supplies · Autonomous driving DC distribution power generation • PFC • EMI/EMC • Inverter / motor drives • Shipping/Rail Converter storage Adaptive cruise control • UPS Radar test applications GaN / SiC SiC GaN

Medium to High Voltages



SiC in Automotive: Main Inverter as the Major Market Opportunity



Higher efficiency =

- ✓ Battery size reduction
- ✓ Cost savings
- ✓ Range extension

Component	Power (kW)	Fraction 6" wafer*	Comment
Main inverter	20 ~ 150	0.1 ~ 0.5	Brings energy from battery to the electric motor
DC-DC Converter	1 ~ 3	<0.01	Brings energy from battery for car electronics
On Board Charger (OBC)	5 ~ 30	0.01	Brings 240 V AC energy from wall plug to battery
(Quick) Charging Pole	30 ~ 300	0.1 ~ 1	Brings 1–3 kV DC energy directly from grid to battery

^{*} Back-of-the-envelope order-of-magnitude estimates



AIXTRON INVESTOR PRESENTATION 30

Our technology. YOUR FUTURE.

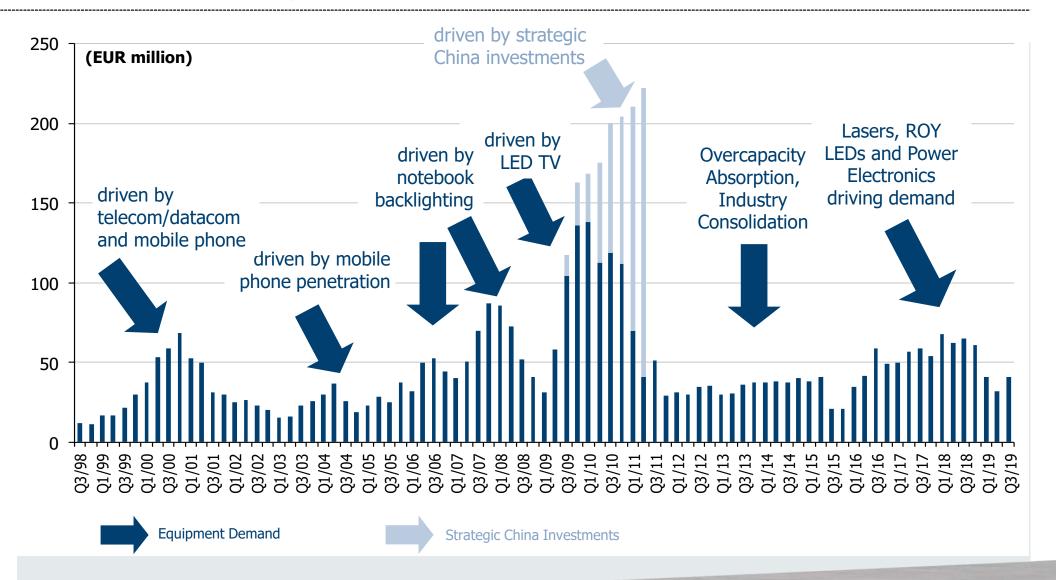


AIXTRON Competitive Landscape

		USA	Europe	China	Korea	Japan
Opto	GaAs/InP Optoelectronics, ROY LED	Veeco				TAIYO NIPPON SANSO The Gas Professionals
	GaN LED	Veeco		TOPEC		TAIYO NIPPON SANSO The Gas Professionals
Power	GaN Power	Veeco				TAIYO NIPPON SANSO The Gas Professionals
	SiC Power		L PE			TOKYO ELECTRON NUFLARE
OLED		APPLIED MATERIALS. **MATERIALS.** **Mateeva**			Your Artistic Solution	CANON TOKKI CORPORATION



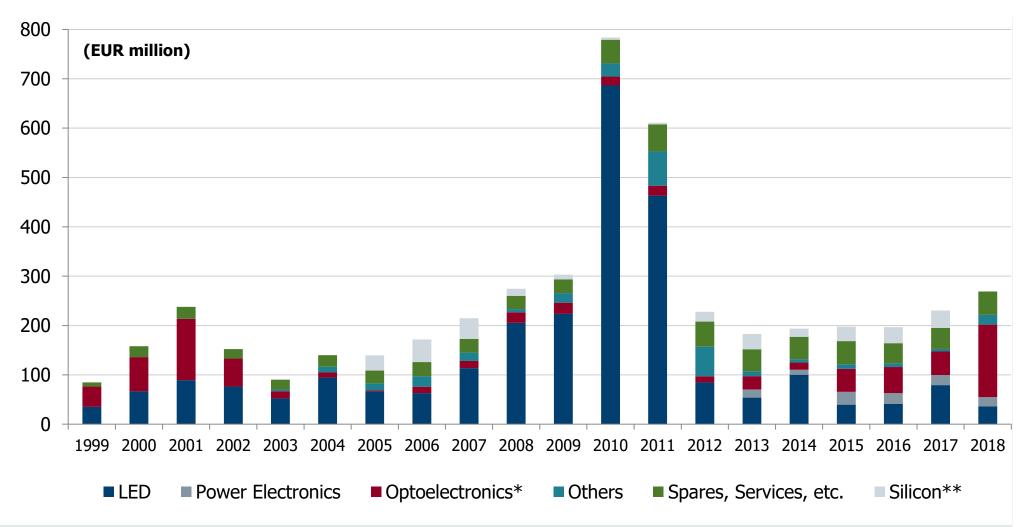
Order Intake per Quarter (Equipment Only)





FINANCIALS

Annual Total Revenues by Application (including spares)



^{*} Optoelectronics includes applications in Consumer Optoelectronics, Telecom/Datacom and Solar



^{**} Silicon: ALD/CVD product line sold in 2017

Consolidated Income Statement*

(€ million)	2018	2017	2016
Revenues	268.8	230.4	196.5
Cost of sales	151.2	156.4	140.2
Gross profit	117.6	74.0	56.3
%	44%	32%	29
Selling expenses	9.4	10.2	13.8
General & admin expenses	18.4	17.1	17.1
R&D	52.2	68.8	53.9
Net other operating income	3.8	27.0	7.2
EBIT	41.5	4.9	-21.4
%	15%	2%	-11%
Net result	45.9	6.5	-24.0
%	17%	3%	-12 /



Balance Sheet*

(€ million)	31/12/18	31/12/17	31/12/16
Property, plant & equipment	63.1	64.3	74.2
Goodwill	71.6	71.2	74.6
Other intangible assets	2.1	1.8	5.4
Others	13.3	4.0	2.4
Non-current assets	150.1	141.3	156.5
Inventories	73.5	43.0	54.2
Trade receivables	40.1	19.3	60.2
Others	11.5	5.0	5.3
Cash & Cash Deposits	263.7	246.5	160.1
Current Assets	388.8	313.8	279.7
Equity	429.7	368.9	369.7
Non-current liabilities	1.8	2.0	4.2
Trade payables	27.8	14.3	14.6
Contract liabilities for advance payments	53.3	30.3	26.1
Others	26.3	39.7	21.6
Current liabilities	107.4	84.2	62.3
Balance Sheet total	538.9	455.1	436.2



Consolidated Statement of Cash Flows*

(€ million)	2018	2017	2016
Cash Flow from operating activities	13.0	70.1	-37.7
Cash Flow from investing activities	-16.1	40.7	43.4
Cash Flow from financing activities	10.4	1.2	0.3
Exchange rate changes	2.4	-5.5	-2.3
Net change in Cash & Cash Equivalents	9.7	106.5	3.7
Cash & Cash Equivalents (beginning of period)	226.5	120.0	116.3
Cash & Cash Equivalents (end of period)	236.2	226.5	120.0
Change in Cash deposits	7.5	-19.5	-52.8
Free Cash Flow**	4.4	91.4	-42.9
Capex	9.2	9.7	5.3



^{**)} Operating CF, CapEx and Capital Divestments

Financial Calendar & Contact Data

• February 27, 2020 FY/2019 Results, Conference Call

April 30, 2020 Q1/2020 Results, Conference Call

May 20, 2020 Annual General Meeting, Aachen, Germany

October 29, 2020 9M/2020 Results, Conference Call

February 2021 FY/2020 Results, Conference Call

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Technology. Materials. Performance.

